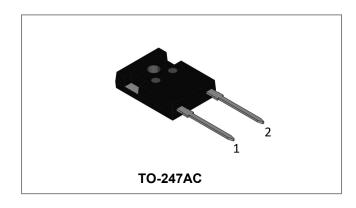






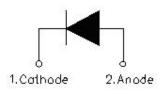
# SDUR75H65W ULTRAFAST RECTIFIER



# **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

#### **Circuit Diagram**



#### **Features**

- Ultra-Fast switching
- High current capability
- Low reverse leakage current
- High surge current capability
- Terminals finish: Tin Lead-free plated
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### Maximum Ratings(limiting values, TC =25°C unless otherwise specified)

Characteristics	Symbol	Condition Max		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	650	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	Tc=80°C, In DC	75	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse	500	Α

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 75A, Pulse, T <sub>J</sub> = 25°C	2.20	2.75	V
	V <sub>F2</sub>	@ 75A, Pulse, T <sub>J</sub> = 125°C	1.90	2.20	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R$ $T_J = 25^{\circ}C$	0.04	5	uA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125$ °C	0.03	1	mA
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =500mA,I <sub>R</sub> =1A,and I <sub>rm</sub> =250mA	38	50	ns

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com
     sales@ smc-diodes.com



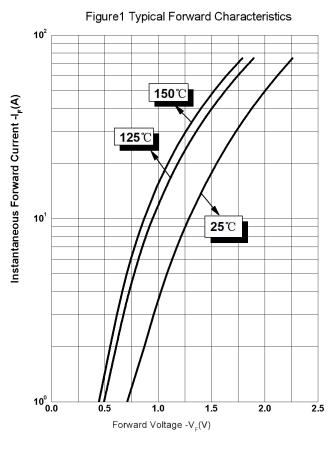


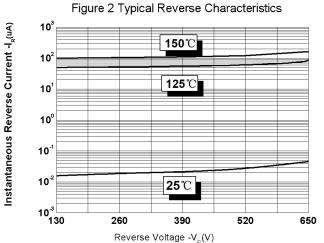


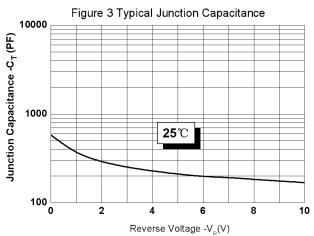
# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	0.34	°C/W
Approximate Weight	wt	-	6.28	g
Case Style	TO-247AC			

# **Ratings and Characteristics Curves**







<sup>•</sup> China - Germany - Korea - Singapore - United States •

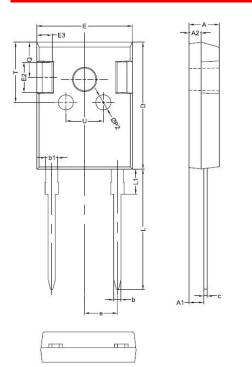
<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •

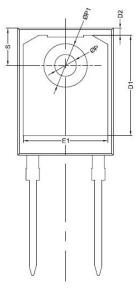






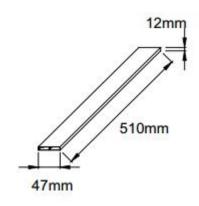
#### **Mechanical Dimensions TO-247AC**



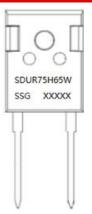


CVMDOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A1	2.20	2.41	2.61	
A2	1.90	2.00	2.10	
b	1.10	1.20	1.35	
b1	1.80	2.00	2.20	
С	0.50	0.60	0.75	
D	20.30	21.00	21.20	
D1		16.58		
D2 E		1.17		
Е	15.60	15.80	16.00	
E1		14.02		
E2		5.00		
E3		2.50		
е		5.44		
L	19.42	19.92	20.42	
L1		4.13		
Р	3.50	3.60	3.70	
P1	7.1	7.19	7.40	
P2		2.50		
Q		5.80		
Q S T	6.05	6.15	6.25	
T		10.00		
U		6.20		

### **Tube Specification**



# **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type 75 = Forward Current (75A) H = H 65 = Reverse Voltage (650V)

 W
 = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

### **Ordering Information**

Device	Package	Shipping	
SDUR75H65W	TO-247AC(Pb-Free)	25pcs / tube	

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •









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